

Band Gap Determination from Diffuse Reflectance Measurements of Irradiated Lead Borate Glass System Doped with TiO₂ by Using Diffuse Reflectance Technique

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ABSTRACT

Ultraviolet-visible UV-Vis diffuse reflectance measurements of irradiated lithium tetra-borate glass have been acquired using. Evolution 600 Spectrophotometer equipped with praying Mantis Diffuse Reflectance Accessory DRA base upon the onset of the diffuse reflectance spectra of the powdered or bulk materials. Also the absorption edge and band gap energies of the prepared glass were determined. The optical energy gap is calculated and found to be (3.0 - 3.5) eV. Which is in close agreement to the one calculated for r = 1/2, *i.e.* the transition mechanism, is accordingly direct allowed transition. The density increases from 3.1 to 3.9 gm/cm³ for the undoped and doped glass.

Keywords: Diffuse Reflectance Accessory; Optical Gap; Borate-Lead-Titanium-Glasses Gamma Radiation

1. Introduction

Measurement of diffuse reflectance with UV-visible spectrophotometer is a standard technique in the determination of the absorption properties of materials. In the case of semiconductors for water splitting, the properties that can potentially be estimated from the diffuse reflectance, are the band-gap energy and the absorption coefficient. Determination of the band gap from the measurement of the diffuse reflectance of a powder sample is a standard technique [1,2]. The powder sample has to be sufficiently thick that all incident light is absorbed or scattered before reaching the back surface of the sample; typically a thickness of 1 - 3 mm is required. It may also be reasonable to apply this method to coatings that are sufficiently thick to absorb or scatter the entire incident light. Titanium dioxide (TiO₂) has been used previously for the production of bioactive and biocompatible phosphate-based glasses. TiO₂ acts as a nucleating agent, and although it is miscible in the molten glass, it induces phase separation during cooling of the melt. It was observed that the addition of 0.5 mol% TiO₂ enhanced the bioactivity which started to decrease upon further increase of the TiO₂ content [3]. Glass materials are one of the possible alternatives to concrete because they can be transparent to visible light and their properties can be modified by composition and preparation techniques. Boric oxide, B₂O₃, acts as one of the most important glass formers and flux materials. Melts with compositions rich in B_2O_3 exhibit rather high viscosity and tend to be the formation of glasses. In crystalline form, on the other hand, borates with various compositions are of exceptional importance due to their interesting linear and nonlinear optical properties. The boron atom usually coordinates with either three or four oxygen atoms forming $[BO_3]^3$ or $[BO_4]^5$ structural units. Furthermore, these two fundamental units can be arbitrarily combined to form different BxOy structural groups [4]. Good reviews on radiation shielding borate glass development have been published recently by several authors [5-8]. These results show that the borate glass can be used in radiation shielding materials.

The purpose of this paper is to demonstrate a method by which the band gap can be derived from measurements of diffuse reflectance. To this end, measurements of the diffuse reflectance of different titanium concentration are reported. The measurements are first used to check the calculated dependence of the diffuse reflectance on titanium concentration, after that studying the effect of gamma radiation on the prepared glass.

2. Experimental

The glass samples of the formula $70Li_2B_4O_7$ - $30Pb_3O_4$ dopped with different concentration of TiO₂ where 0.1,

0.2 and 0.3 mol% have been prepared by the melt quenching technique. The mixture is melted in porcelain crucible at about 1100 K for about 60 min to homogenize the melt. The melt was quickly quenched by pouring on to a stainless steel plate and covering with another stainless steel plate and the random pieces of samples thus formed were collected. Density at room temperature was measured by following Archimedes principle using a sensitive single pan balance. The carbon tetrachloride, CCl_4 (density = 1.595 m/cc) was used as an immersion liquid. Irradiations were carried out with gamma radiation in the ⁶⁰Co gamma chamber 4000 A for the dose rates 1.23 Gy/sec. The absorption spectra of the unirradiated and irradiated were measured through the wavelength range (200 - 900) using Evolution 600 EV-600 (located at NCRRT, EGYPT), ultraviolet/visible, spectrophotometer wavelength ranged from 200 - 900 nm is used for scanning the absorption spectra and measuring the optical density at λ_{max} of the prepared glass.

3. Results and Discussion

3.1. Density, Molar Volume

The value of density and molar volume of the prepared glasses are shown on **Figures 1** and **2** illustrate the density of $70Li_2B_4O_7$ - $30Pb_3O_4$ doped with different concentration of TiO₂. The density increase from 3.1 to 3.9 gm/cm³ for the undoped and doped glass and the decrease of molar volume is expected result due to the highly molecular weight of TiO₂. It is observed that, for unirradiated samples, the addition of TiO₂ to the prepared glass leads to the increase of the number of ions in the system which decreases the inter-ionic distance or due to the formation of Pb-O covalent bond in ternary lead



Figure 1. Variation of density and molar volume with TiO₂% uirradiaded for the glass system LTbPTiO₂.



Figure 2. Variation of density and molar volume with $TiO_2\%$ irradiaded with 3 Mrad gamma dose for the glass system LTbPTiO₂.

lithium borate glass which leads to close the structure of the glasses. As a result, the molar volume of LTbPTiO₂ decreased and consequently its density increased in the range of $25\% \pm 1\%$ for each molar volume and density as shown in **Figure 1**, this means that TiO₂ can be considered as an indication of an increase in the number of the non-bridging oxygen associated with a structure contraction.

3.2. Effect of Irradiation

Irradiation with gamma rays are assumed to create displacements, electronic defects and/or breaks in the network bonds, which allow the structure to relax and fill the relatively large interstices that exist in the intercomnected network of boron and oxygen atoms causing a compaction of the volume [9].

Shelby [10] suggested that the boron-oxygen bond is more likely to be affected by irradiation. Damage by an irradiation species can cause the compaction of B_2O_3 by the breaking of the bonds between triagonal elements, allowing the formation of different ring configurations. This result is in agreement with the results obtained by El-Batal *et al.* [11] where they found that nuclear irradiation is believed to cause noticeable structural changes.

4. Band Gap Determination

4.1. Rule of the Band Gap and Band Tail

Figures 3 and **4** show the reflectance (R) and transmittance (T), which are measured at room temperature at normal incident as a function of wavelength in the spectral range from 200 nm up to 900 nm for the LTbPTiO₂ glass system. The optical absorption coefficient, α , which is the relative rate of decrease in light intensity along its path of propagation, was calculated from the transmit



Figure 3. The transmitance T% and the Reflectance R% of unirradiated LTbPTiO₂ with different concentration of TiO₂.



Figure 4. The transmitance T% and the Reflectance R% of 3 Mrad gamma irradiated LTbPTiO₂ with different concentration of TiO₂.

tance and reflectance data in the wavelength range 200 - 900 nm. The nature of the optically induced transitions was determined from these data [12].

$$\alpha(h\nu) = \frac{1}{d} \ln\left(\frac{\left(100 - R\right)^2}{T}\right) \tag{1}$$

where T is the transmittance, R is the reflectance, and d is the sample thickness. The optical absorption coefficient of glass system near the fundamental absorption edge was found to be exponentially dependent on the photon energy. The exponential dependence of the optical absorption coefficient may arise from the electronic transitions between the localized states, which have tailed off in the band gap. To obtain the optical gap E_{op} for the investigated glass Equation (2) will be used, [13] but, which value of "r" must be applied to have the exact value of the optical band gap? Accordingly we may say that it is not adequate alone to be used for the determination of both the type of conduction and the optical gap; it is necessary but not sufficient [14]. Different value of "r" was applied to the experimental data as present in **Tables 1** and **2**.

$$\alpha(h\nu). \quad h\nu \approx B(h\nu - E_{op})' \tag{2}$$

where *B* is a constant, r is an index, which assumes the values 1/2, 3/2, 2 or 3, depending on the nature of the electronic transition responsible for absorption mechanism of electron transition. The exponent r = 1/2, 3/2 for direct transition is allowed or forbidden in the quantum mechanical sense, and r = 2, 3 for allowed and forbidden indirect transition, respectively [15].

The optical gap E_{op} for each samples obtained from Equation (2) will be used, but, which value of "r" must be applied to have the exact value of the optical band gap, different values of "r" was applied to the present experimental data for glass system LTbPTiO₂, It is found that the obtained optical gap changes with changing the value of the exponent "r" as shown in **Tables 1** and **2**.

On the other hand, **Figure 5** shows the variation of $\ln \alpha$ with incident photon energy hv for the glass system LTbPTiO₂, as was found to be linear in the absorption region near the fundamental absorption edge. The absorption edge is found to be exponentially dependent on the incident photon energy and obeys the empirical Urbach rule Equation (3) [15,16]. The width of the localized states E_e (band tail energy or Urbach energy) estimated from the inverse slopes of $\ln \alpha$ versus hv.



Figure 5. The relation between absorption coefficient $\ln \alpha$ and energy *hv* for the prepared glass system.

TiO ₂ mol %	optical band gap from å ₂ eV	optical band gap $(E_{op})^{1/2} \text{ eV}$	optical band gap $(E_{op})^{1/3} \mathrm{eV}$	optical band gap $(E_{op})^{2/3} \mathrm{eV}$	optical band gap $(E_{op})^2 \text{ eV}$	Urbach energy $(E_e) \text{ eV}$
0	3.5	2.8	2.6	2.94	3.5	0.4
0.1	3.27	2.66	2.1	2.78	3.3	0.42
0.2	3.1	2.5	2	2.8	3.26	0.46
0.3	3	2.42	1.76	2.7	3.2	0.51
SUM.	3.21	2.6	2.11	2.82	3.315	

Table 1. The obtained values of optical gap at different values of the exponent (r) for Unirradiated LTbPTiO₂ system.

Table 2. The obtained values of optical gap at different values of the exponent (r) for 3 Mrad gamma irradiation of LTbPTiO₂ system.

T iO ₂ mol %	optical band gap from å ₂ eV	optical band gap $(E_{op})^{1/2} \text{ eV}$	optical band gap $(E_{op})^{1/3} \text{ eV}$	optical band gap $(E_{op})^{2/3} \text{ eV}$	optical band gap $(E_{op})^2 \text{ eV}$	Urbach energy $(E_e) \text{ eV}$
0	3.4	2.9	2.4	3.1	3.5	0.42
0.1	3.3	2.71	2.2	2.9	3.3	0.45
0.2	3.15	2.65	1.92	2.78	3.2	0.49
0.3	3.05	2.6	1.6	2.71	3	0.53
SUM.	3.23	2.71	2.03	2.78	3.25	

$$\alpha(hv) = \alpha \exp(hv/E_e) \tag{3}$$

Tables 1 and **2** show that, the obtained values of the optical gap have changed according to the value of the exponent "*r*". This is together with that the change in the value of Regression coefficient does not give good indication of which is the real value of "*r*" which can be selected. So, Equation (2) may be used only for determination the type of conduction mechanism and the optical gap itself should be determined using another parameter, by which the exact value of exponent can be selected. The selected parameter is the imaginary part of the dielectric constant ε_2 , which is a function of refractive index *n*, and extinction coefficient *k*;

$$\varepsilon_2 = 2nk^2 \tag{4}$$

Figure 6 shows the relation between $(\alpha hv)^2$ versus (hv) plot according to Equation (2). The direct optical energy gap can be obtained from the intercept of the resulting straight lines with the energy axis at $(\alpha hv)^2 = 0$. Plotting the imaginary part ε_2 versus the photon energy as shown in **Figure 7**, the optical energy gap obtained and found to be 3.0 - 3.3 eV.

Comparing the optical band gap which obtained from **Figure 5** and that's from **Figure 7** and the data in both **Tables 1** and **2**, we can see the energy gap is close agreement to the one calculated for r = 1/2, *i.e.* the transition mechanism is accordingly direct allowed transition.

4.2. Effect of Radiation

The optical band gap E_{opt} in Urbach region Figures 8 and



Figure 6. The relation between energy $hv \, eV$ and $(\alpha E)^2$ for unirradiated glass (*R*: is the reability of fitting, best fitting *R* = ±1).

9 of the glasses can be obtained according to its dependence on absorption coefficient á and the energy $h\mu$ of the incident photon [15]. After irradiation, the defect centers formed by charge trapping of the radiolytic electrons or holes often have electronic states in the gap between the valence and conduction bands. So, optical photons may induce transition between the valence band and the defect levels or from the defect levels to excited states or the conduction band. **Figure 8** shows the band gap has decreased, and the width of the energy tail has increased after irradiation. These changes can be explained by an



Figure 7. The relation between Optical dielectric constant ε_2 and phonon energy for irradiated LTBPTiO₂ system.



Figure 8. Variation of optical band gap E_{op} and band tail E_e with TiO₂ mol% for unirradiated glass system LTbPTiO₂.

increased electronic density after gamma irradiation. The interaction of gamma rays with materials is dominated by the Compton Effect, the cross section of which is proportional to the atomic number. Hence, there are an increasing number of energetic electrons in the glass network with increasing TiO₂ content. This electronic ionization will increase the electronic transitions between localized states, so that the band gap decreases and the width of the energy tail increases after irradiation.

5. Conclusion

Titanium oxide is used in the composition of some glasses in order to achieve and tailoring all together a certain optical glass features. Density and band tail results show an increase with increasing gamma radiation doses. The molar volume and the optical gap show opposite trend.



Figure 9. Variation of optical band gap E_{op} and band tail E_e with TiO₂ mol% for 3 Mrad gamma irradiation for the glass system LTbPTiO₂.

The addition of titanium to the glass makes it sensitive to radiation on the other hand titanium dioxide glass can be used as electrolytes where it has high conductivity.

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